

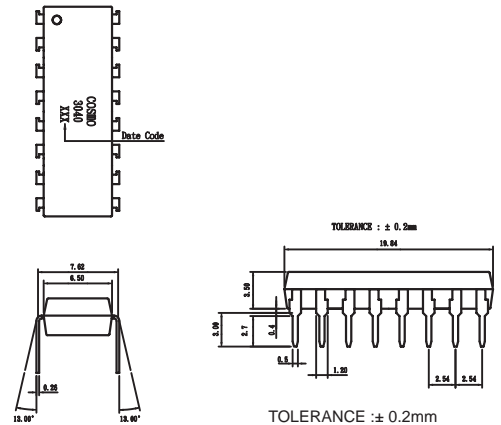
Features

1. Current transfer ratio
(CTR:MIN.60% at $I_F = \pm 1\text{mA}$ $V_{ce} = 5\text{V}$)
2. High isolation voltage between input and output
(Viso:5000Vrms).
3. Compact dual-in-line package.
4. Ac input.
5. Available package : DIP/ SMD/ H. (For Package Dimension please refer to page 84)

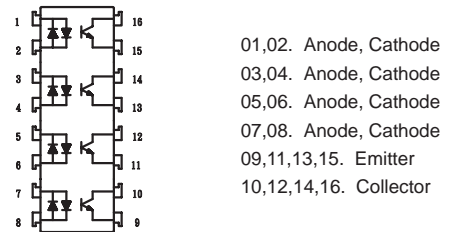
Applications

1. Programmable Controller Applications for Low Input Photocouplers and High V_{ceo} Photocouplers.
2. Telephone sets, telephone exchangers.
3. System appliances, Limit Switches, Sensors, Thermostats Transducers etc.
4. Signal transmission between circuits of different potentials and impedances.

Outside Dimension : Unit (mm)



Schematic : Top View



01,02. Anode, Cathode
03,04. Anode, Cathode
05,06. Anode, Cathode
07,08. Anode, Cathode
09,11,13,15. Emitter
10,12,14,16. Collector

Absolute Maximum Ratings

($T_a = 25^\circ\text{C}$)

Parameter		Symbol	Rating	Unit
Input	Forward current	I_F	± 50	mA
	Peak forward current	I_{FM}	± 1	A
	Power dissipation	P_D	70	mW
Output	Collector-emitter voltage	V_{CEO}	60	V
	Emitter-collector voltage	V_{ECO}	6	V
	Collector current	I_C	50	mA
	Collector power dissipation	P_C	150	mW
Total power dissipation		P_{tot}	200	mW
Isolation voltage 1 minute		Viso	5000	Vrms
Operating temperature		T_{opr}	-30 to +100	$^\circ\text{C}$
Storage temperature		T_{stg}	-55 to +125	$^\circ\text{C}$
Soldering temperature 10 second		T_{sol}	260	$^\circ\text{C}$

Electro-optical Characteristics

($T_a = 25^\circ\text{C}$)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V_F	$I_F = \pm 20\text{mA}$	—	1.2	1.4	V
	Peak forward voltage	V_{FM}	$I_{FM} = \pm 0.5\text{A}$	—	—	3.5	V
	Terminal capacitance	C_t	$V = 0, f = 1\text{kHz}$	—	30	—	pF
Output	Collector dark current	I_{CEO}	$V_{CE} = 20\text{V}, I_F = 0$	—	—	0.1	μA
Transfer characteristics	Current transfer ratio	CTR	$I_F = \pm 1\text{mA}, V_{CE} = 5\text{V}$	60	—	600	%
	Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_F = \pm 20\text{mA}, I_C = 1\text{mA}$	—	0.1	0.3	V
	Isolation resistance	Riso	DC500V	5×10^{10}	10^{11}	—	ohm
	Floating capacitance	C_f	$V = 0, f = 1\text{MHz}$	—	0.6	1.0	pF
	Cut-off frequency	f_c	$V_{CC} = 5\text{V}, I_C = 2\text{mA}, R_L = 100\text{ohm}$	—	80	—	kHz
	Response time (Rise)	t_r	$V_{CE} = 2\text{V}, I_C = 2\text{mA}, R_L = 100\text{ohm}$	—	5	20	μs
	Response time (Fall)	t_f		—	4	20	μs

Fig.1 Current Transfer Ratio vs. Forward Current

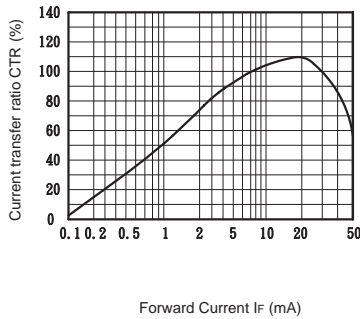


Fig.2 Collector Power Dissipation vs. Ambient Temperature

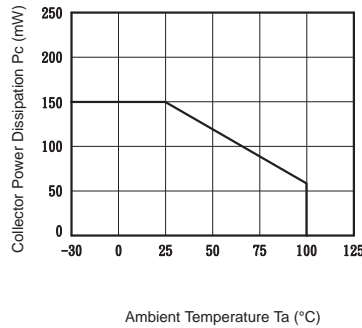


Fig.3 Collector Dark Current vs. Ambient Temperature

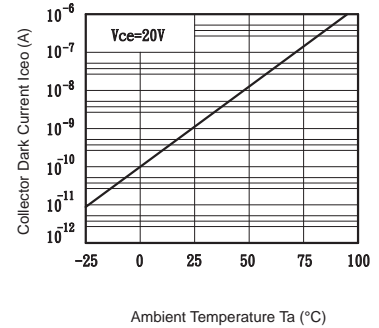


Fig.4 Forward Current vs. Ambient Temperature

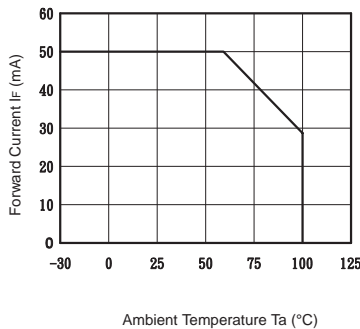


Fig.5 Forward Current vs. Forward Voltage

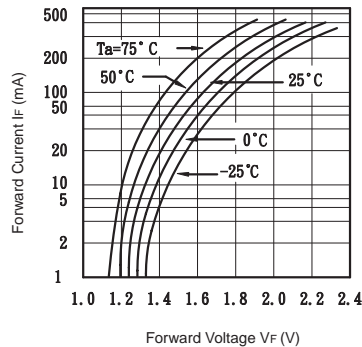


Fig.6 Collector Current vs. Collector-emitter Voltage

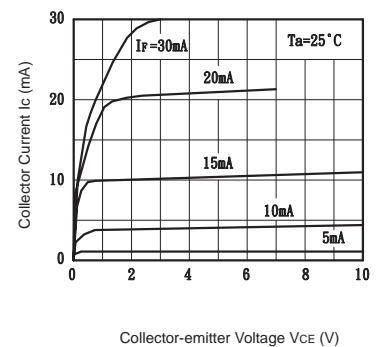


Fig.7 Relative Current Transfer Ratio vs. Ambient Temperature

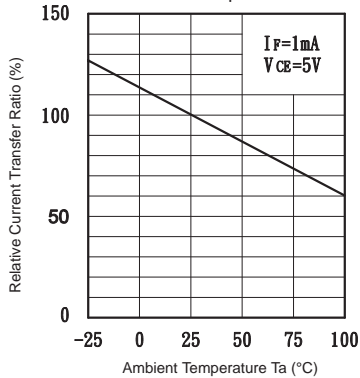


Fig.8 Collector-emitter Saturation Voltage vs. Ambient Temperature

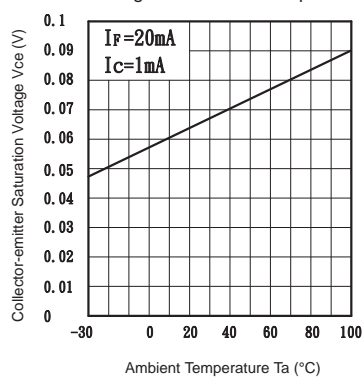


Fig.9 Collector-emitter Saturation Voltage vs. Forward Current

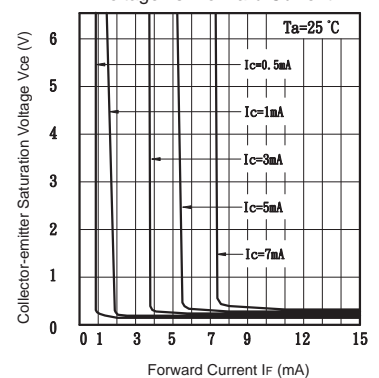


Fig.10 Response Time vs. Load Resistance

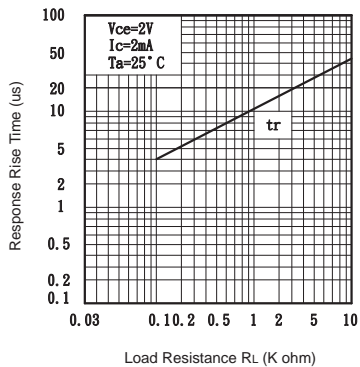


Fig.11 Response Time vs. Load Resistance

